CMOS Digital Integrated Circuits Silicon Monolithic

# TC7SH17F

### 1. Functional Description

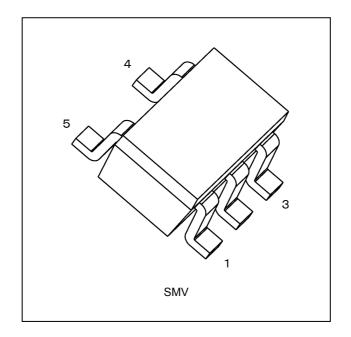
Schmitt Buffer

#### 2. Features

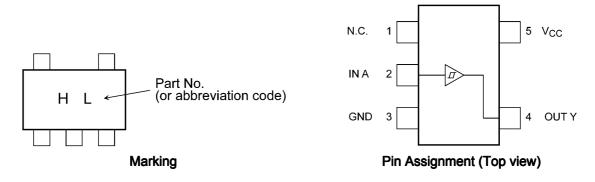
- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 2)
- (3) High speed operation:  $t_{pd} = 5.5$  ns (typ.) ( $V_{CC} = 5.0$  V,  $C_L = 15$  pF)
- (4) Low power dissipation:  $I_{CC} = 2.0 \ \mu A \ (max) \ (T_a = 25 \ ^\circ C)$
- (5) Wide operating voltage range:  $V_{CC} = 2.0$  to 5.5 V
- (6) High noise immunity:  $V_{\text{NIH}} = V_{\text{NIL}} = 28 \% V_{\text{CC}}$  (min)
- (7) 5.5 V tolerant inputs
- Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.

Note 2: For devices with the ordering part number ending in J(CT.  $T_{opr}$  = -40 to 85 °C for the other devices.

### 3. Packaging



## 4. Marking and Pin Assignment



### 5. IEC Logic Symbol



#### 6. Truth Table

| A | Y |
|---|---|
| L | L |
| Н | Н |

## 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

| Characteristics                 | Symbol           | Note     | Rating                        | Unit |
|---------------------------------|------------------|----------|-------------------------------|------|
| Supply voltage                  | V <sub>CC</sub>  |          | -0.5 to 7.0                   | V    |
| Input voltage                   | V <sub>IN</sub>  |          | -0.5 to 7.0                   |      |
| DC output voltage               | V <sub>OUT</sub> |          | -0.5 to V <sub>CC</sub> + 0.5 |      |
| Input diode current             | l <sub>IK</sub>  |          | -20                           | mA   |
| Output diode current            | I <sub>ОК</sub>  | (Note 1) | ±20                           |      |
| DC output current               | I <sub>OUT</sub> |          | ±25                           |      |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>  |          | ±50                           |      |
| Power dissipation               | PD               |          | 200                           |      |
| Storage temperature             | T <sub>stg</sub> |          | -65 to 150                    |      |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 

## 8. Operating Ranges (Note)

| Characteristics       | Symbol           | Note     | Test Condition | Rating               | Unit |
|-----------------------|------------------|----------|----------------|----------------------|------|
| Supply voltage        | V <sub>CC</sub>  |          | —              | 2.0 to 5.5           | V    |
| Input voltage         | V <sub>IN</sub>  |          | _              | 0 to 5.5             |      |
| Output voltage        | V <sub>OUT</sub> |          | —              | 0 to V <sub>CC</sub> |      |
| Operating temperature | T <sub>opr</sub> | (Note 1) | —              | -40 to 125           | °C   |
|                       |                  | (Note 2) |                | -40 to 85            |      |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: For devices with the ordering part number ending in J(CT).

Note 2: For devices except those with the ordering part number ending in J(CT).

### 9. Electrical Characteristics

## 9.1. DC Characteristics (Unless otherwise specified, Ta = 25 °C)

| Characteristics            | Symbol          | Test Conditior                           | 1                        | V <sub>CC</sub> (V) | Min  | Тур. | Max  | Unit |
|----------------------------|-----------------|--|--------------------------|---------------------|------|------|------|------|
| Positive threshold voltage | VP              | —  |                          | 3.0                 | _    | —    | 2.20 | V    |
|                            |                 |  |                          | 4.5                 | —    | —    | 3.15 |      |
|                            |                 |  |                          | 5.5                 | _    | _    | 3.85 |      |
| Negative threshold voltage | V <sub>N</sub>  | —  |                          | 3.0                 | 0.90 | —    | _    | V    |
|                            |                 |  |                          | 4.5                 | 1.35 | —    | _    |      |
|                            |                 |  |                          | 5.5                 | 1.65 | _    | _    |      |
| Hysteresis voltage         | V <sub>H</sub>  | —  |                          | 3.0                 | 0.30 | _    | 1.20 | V    |
|                            |                 |  |                          | 4.5                 | 0.40 | _    | 1.40 |      |
|                            |                 |  |                          | 5.5                 | 0.50 | _    | 1.60 |      |
| High-level output voltage  | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IH</sub>        | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9  | 2.0  | _    | V    |
|                            |                 |  |                          | 3.0                 | 2.9  | 3.0  | _    |      |
|                            |                 |  |                          | 4.5                 | 4.4  | 4.5  | _    |      |
|                            |                 |  | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.58 | _    | _    |      |
|                            |                 |  | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.94 | _    | _    |      |
| Low-level output voltage   | V <sub>OL</sub> | V <sub>IN</sub> = V <sub>IL</sub>        | I <sub>OL</sub> = 50 μA  | 2.0                 | _    | 0.0  | 0.1  | V    |
|                            |                 |  |                          | 3.0                 | _    | 0.0  | 0.1  |      |
|                            |                 |  |                          | 4.5                 | _    | 0.0  | 0.1  |      |
|                            |                 |  | I <sub>OL</sub> = 4 mA   | 3.0                 | _    | _    | 0.36 |      |
|                            |                 |  | I <sub>OL</sub> = 8 mA   | 4.5                 | _    | _    | 0.36 |      |
| Input leakage current      | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND           |                          | 0 to 5.5            | _    | _    | ±0.1 | μA   |
| Quiescent supply current   | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND |                          | 5.5                 |      | _    | 2.0  | μA   |

## 9.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

| Characteristics            | Symbol          | Test Con                                 | dition                   | V <sub>CC</sub> (V) | Min  | Мах  | Unit |
|----------------------------|-----------------|--|--------------------------|---------------------|------|------|------|
| Positive threshold voltage | V <sub>P</sub>  | _  |                          | 3.0                 | _    | 2.20 | V    |
|                            |                 |  |                          | 4.5                 | _    | 3.15 |      |
|                            |                 |  |                          | 5.5                 | _    | 3.85 |      |
| Negative threshold voltage | V <sub>N</sub>  | _  |                          | 3.0                 | 0.90 | _    | V    |
|                            |                 |  |                          | 4.5                 | 1.35 | _    |      |
|                            |                 |  |                          | 5.5                 | 1.65 | _    |      |
| Hysteresis voltage         | V <sub>H</sub>  | _  |                          | 3.0                 | 0.30 | 1.20 | V    |
|                            |                 |  |                          | 4.5                 | 0.40 | 1.40 |      |
|                            |                 |  |                          | 5.5                 | 0.50 | 1.60 | 1    |
| High-level output voltage  | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IH</sub>        | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9  | _    | V    |
|                            |                 |  |                          | 3.0                 | 2.9  | _    |      |
|                            |                 |  |                          | 4.5                 | 4.4  | _    | 1    |
|                            |                 |  | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.48 | _    |      |
|                            |                 |  | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.80 | _    |      |
| Low-level output voltage   | V <sub>OL</sub> | V <sub>IN</sub> = V <sub>IL</sub>        | I <sub>OL</sub> = 50 μA  | 2.0                 | _    | 0.1  | V    |
|                            |                 |  |                          | 3.0                 | _    | 0.1  |      |
|                            |                 |  |                          | 4.5                 | _    | 0.1  |      |
|                            |                 |  | I <sub>OL</sub> = 4 mA   | 3.0                 | _    | 0.44 | 1    |
|                            |                 |  | I <sub>OL</sub> = 8 mA   | 4.5                 | _    | 0.44 | 1    |
| Input leakage current      | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND           | ·                        | 0 to 5.5            |      | ±1.0 | μA   |
| Quiescent supply current   | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND |                          | 5.5                 |      | 20.0 | μA   |

## 9.3. DC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C)

| Characteristics            | Symbol          | Test Con                                 | dition                   | V <sub>CC</sub> (V) | Min  | Мах  | Unit |
|----------------------------|-----------------|--|--------------------------|---------------------|------|------|------|
| Positive threshold voltage | V <sub>P</sub>  | _  |                          | 3.0                 | _    | 2.20 | V    |
|                            |                 |  |                          | 4.5                 | _    | 3.15 |      |
|                            |                 |  |                          | 5.5                 | _    | 3.85 |      |
| Negative threshold voltage | V <sub>N</sub>  | _  |                          | 3.0                 | 0.90 | _    | V    |
|                            |                 |  |                          | 4.5                 | 1.35 | —    |      |
|                            |                 |  |                          | 5.5                 | 1.65 | —    |      |
| Hysteresis voltage         | V <sub>H</sub>  | _  |                          | 3.0                 | 0.30 | 1.20 | V    |
|                            |                 |  |                          | 4.5                 | 0.40 | 1.40 |      |
|                            |                 |  |                          | 5.5                 | 0.50 | 1.60 |      |
| High-level output voltage  | V <sub>OH</sub> | V <sub>IN</sub> = V <sub>IH</sub>        | I <sub>OH</sub> = -50 μA | 2.0                 | 1.9  | _    | V    |
|                            |                 |  |                          | 3.0                 | 2.9  | _    |      |
|                            |                 |  |                          | 4.5                 | 4.4  | _    |      |
|                            |                 |  | I <sub>OH</sub> = -4 mA  | 3.0                 | 2.40 | _    |      |
|                            |                 |  | I <sub>OH</sub> = -8 mA  | 4.5                 | 3.70 | _    |      |
| Low-level output voltage   | V <sub>OL</sub> | V <sub>IN</sub> = V <sub>IL</sub>        | I <sub>OL</sub> = 50 μA  | 2.0                 | _    | 0.1  | V    |
|                            |                 |  |                          | 3.0                 | _    | 0.1  |      |
|                            |                 |  |                          | 4.5                 | _    | 0.1  |      |
|                            |                 |  | I <sub>OL</sub> = 4 mA   | 3.0                 | _    | 0.55 |      |
|                            |                 |  | I <sub>OL</sub> = 8 mA   | 4.5                 | _    | 0.55 |      |
| Input leakage current      | I <sub>IN</sub> | V <sub>IN</sub> = 5.5 V or GND           |                          | 0 to 5.5            | _    | ±2.0 | μA   |
| Quiescent supply current   | I <sub>CC</sub> | V <sub>IN</sub> = V <sub>CC</sub> or GND |                          | 5.5                 | _    | 40.0 | μA   |

Note: For devices with the ordering part number ending in J(CT.

### 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

| Characteristics               | Symbol                             | Note     | Test<br>Condition | V <sub>CC</sub> (V)           | C <sub>L</sub> (pF) | Min | Тур. | Max  | Unit |
|-------------------------------|------------------------------------|----------|-------------------|-------------------------------|---------------------|-----|------|------|------|
| Propagation delay time        | t <sub>PLH</sub> ,t <sub>PHL</sub> |          | —                 | $\textbf{3.3}\pm\textbf{0.3}$ | 15                  | _   | 8.3  | 12.8 | ns   |
|                               |                                    |          |                   |                               | 50                  | _   | 10.8 | 16.3 |      |
|                               |                                    |          |                   | $5.0\pm0.5$                   | 15                  | _   | 5.5  | 8.6  |      |
|                               |                                    |          |                   |                               | 50                  | _   | 7.0  | 10.6 |      |
| Input capacitance             | C <sub>IN</sub>                    |          | _                 |                               |                     | _   | 4    | 10   | pF   |
| Power dissipation capacitance | C <sub>PD</sub>                    | (Note 1) | —                 |                               |                     | _   | 14   | —    | pF   |

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

## 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Note | Test Condition | V <sub>CC</sub> (V)           | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|------|----------------|-------------------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> |      | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 15                  | 1.0 | 15.0 | ns   |
|                        |                                    |      |                |                               | 50                  | 1.0 | 18.5 |      |
|                        |                                    |      |                | $5.0\pm0.5$                   | 15                  | 1.0 | 10.0 |      |
|                        |                                    |      |                |                               | 50                  | 1.0 | 12.0 |      |
| Input capacitance      | C <sub>IN</sub>                    |      | _              |                               |                     | _   | 10   | pF   |

### 9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

| Characteristics        | Symbol                             | Note | Test Condition | V <sub>CC</sub> (V)           | C <sub>L</sub> (pF) | Min | Max  | Unit |
|------------------------|------------------------------------|------|----------------|-------------------------------|---------------------|-----|------|------|
| Propagation delay time | t <sub>PLH</sub> ,t <sub>PHL</sub> |      | —              | $\textbf{3.3}\pm\textbf{0.3}$ | 15                  | 1.0 | 17.0 | ns   |
|                        |                                    |      |                |                               | 50                  | 1.0 | 20.5 |      |
|                        |                                    |      |                | $5.0\pm0.5$                   | 15                  | 1.0 | 11.5 |      |
|                        |                                    |      |                |                               | 50                  | 1.0 | 13.5 |      |
| Input capacitance      | C <sub>IN</sub>                    |      | —              |                               |                     | _   | 10   | pF   |

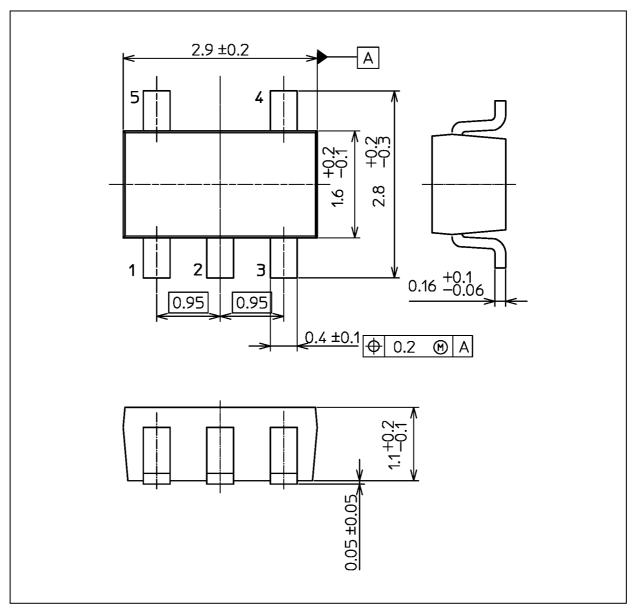
Note: For devices with the ordering part number ending in J(CT.



## TC7SH17F

### **Package Dimensions**

Unit: mm



#### Weight: 14 mg (typ.)

|               | Package Name(s) |  |
|---------------|-----------------|--|
| JEDEC: SOT-25 |                 |  |
| Nickname: SMV |                 |  |

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